

## Features

- Split Gate Trench MOSFET Technology
- Low  $R_{DS(on)}$  & FOM
- Low  $C_{rss}$
- Extremely Low Switching Loss
- Excellent Stability and Uniformity
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

## Maximum Ratings

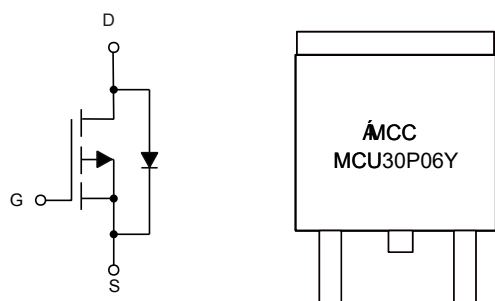
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 20°C/W Junction to Ambient( $t \leq 10s$ )
- Thermal Resistance: 50°C/W Junction to Ambient(Steady-State)
- Thermal Resistance: 1.7°C/W Junction to Case(Steady-State)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	-60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	-30	A
Pulsed Drain Current <sup>(2)</sup>	$I_{DM}$	-120	A
Total Power Dissipation <sup>(3)</sup>	$P_D$	72	W
Single Pulsed Avalanche Energy <sup>(4)</sup>	$E_{AS}$	81	mJ

Note:

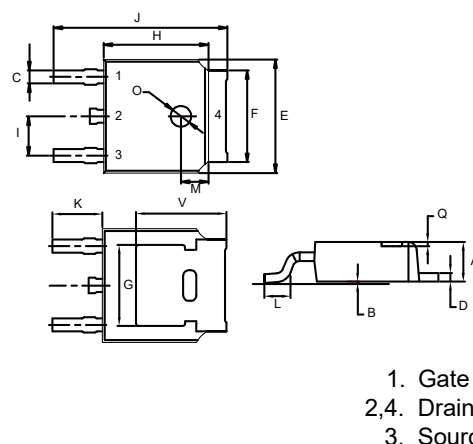
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. Repetitive rating; pulse width limited by max. junction temperature.
3.  $P_D$  is based on max. junction temperature, using junction-case thermal resistance.
4.  $V_{DD}=50V$ ,  $R_G=25\Omega$ ,  $L=0.5mH$ ,  $I_{AS}=18A$ .

•bhfBU'Gfi Wi fY'UbX'A Uf\_]b[ '7 cXY



## P-CHANNEL MOSFET

### DPAK(TO-252)



DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.087	0.094	2.20	2.40	
B	0.000	0.005	0.00	0.13	
C	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
E	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
H	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
M	0.063		1.60		TYP.
O	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

**Electrical Characteristics @ 25°C (Unless Otherwise Specified)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
<b>Static Characteristics</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-60			V
Gate-Source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-60V, V_{GS}=0V$			-1	$\mu A$
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.5	-2.1	-2.7	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-20A$		39	55	m $\Omega$
		$V_{GS}=-4.5V, I_D=-10A$		50	65	m $\Omega$
<b>Diode Characteristics</b>						
Continuous Body Diode Current	$I_S$				-30	A
Diode Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=-20A$			-1.3	V
Reverse Recovery Time	$t_{rr}$	$I_S=-20A, di/dt=100A/\mu s$		19		ns
Reverse Recovery Charge	$Q_{rr}$			3.9		nC
<b>Dynamic Characteristics</b>						
Input Capacitance	$C_{iss}$	$V_{DS}=-30V, V_{GS}=0V, f=1MHz$		1050		pF
Output Capacitance	$C_{oss}$			340		
Reverse Transfer Capacitance	$C_{rss}$			62		
Total Gate Charge	$Q_g$	$V_{DS}=-30V, V_{GS}=-10V, I_D=-20A$		19.3		nC
Gate-Source Charge	$Q_{gs}$			5.3		
Gate-Drain Charge	$Q_{gd}$			3.1		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS}=-30V, V_{GS}=-10V, R_G=3\Omega, I_D=-5A$		5.4		ns
Turn-On Rise Time	$t_r$			23.3		
Turn-Off Delay Time	$t_{d(off)}$			47.2		
Turn-Off Fall Time	$t_f$			37.1		

## Curve Characteristics

Fig. 1 - Typical Output Characteristics

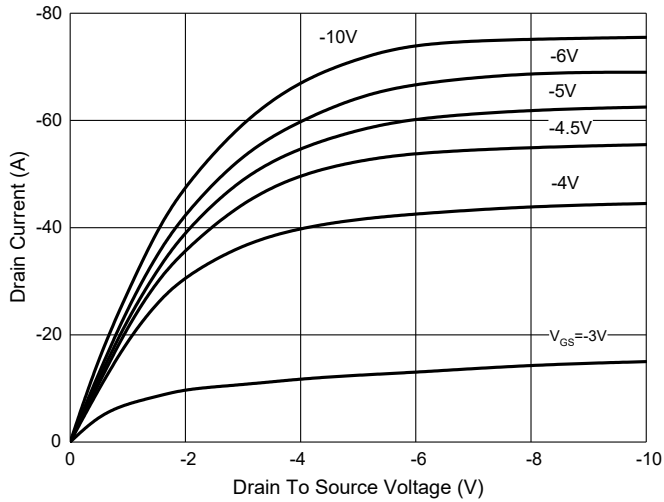


Fig. 2 - Transfer Characteristics

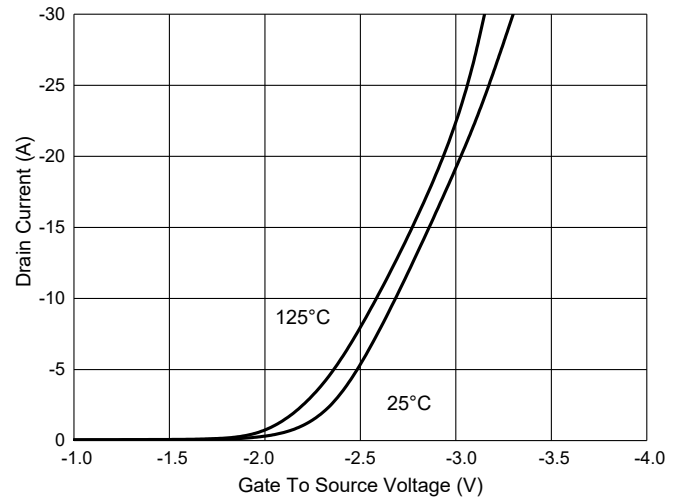


Fig. 3 -  $R_{DS(ON)} - V_{GS}$

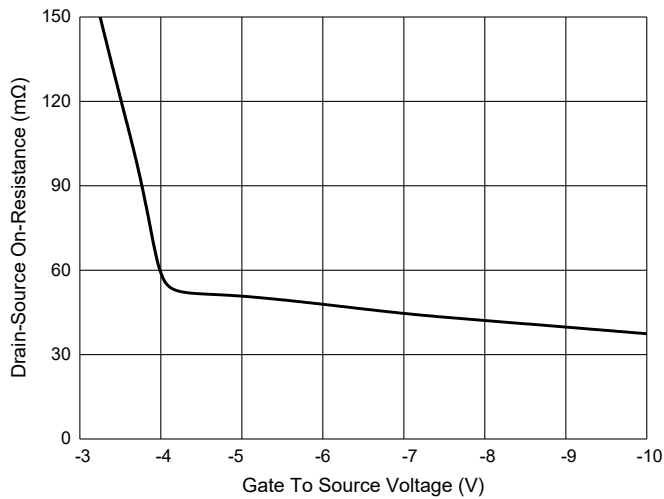


Fig. 4 - Normalized On Resistance Characteristics

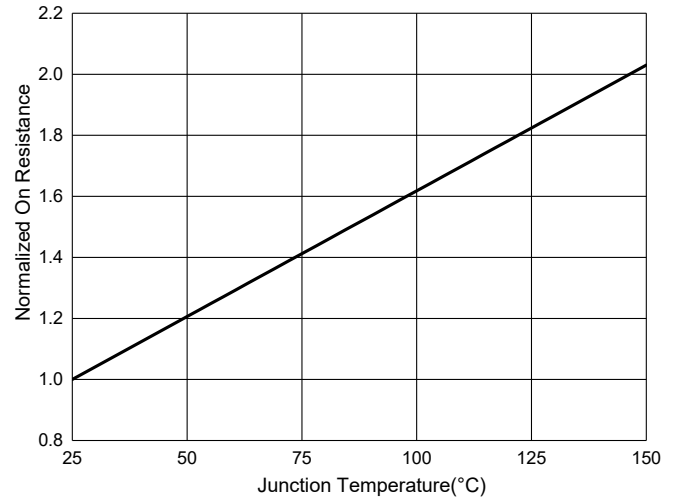


Fig. 5 - Capacitance Characteristics

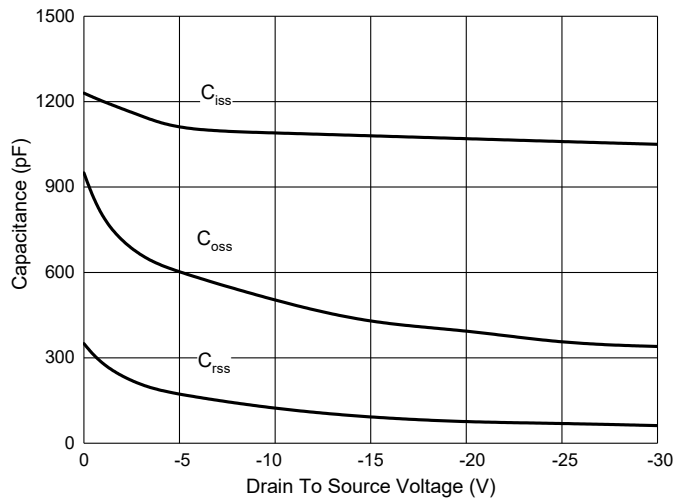
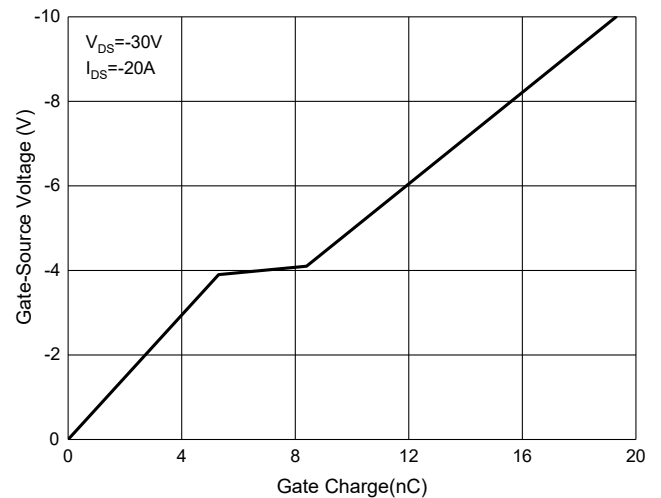


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Safe Operation Area

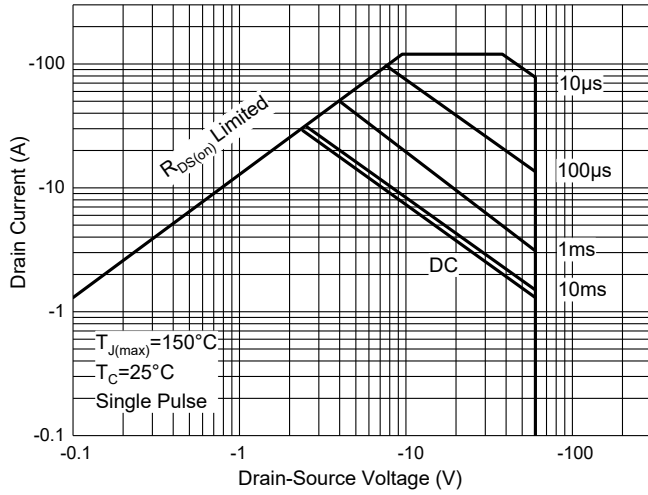
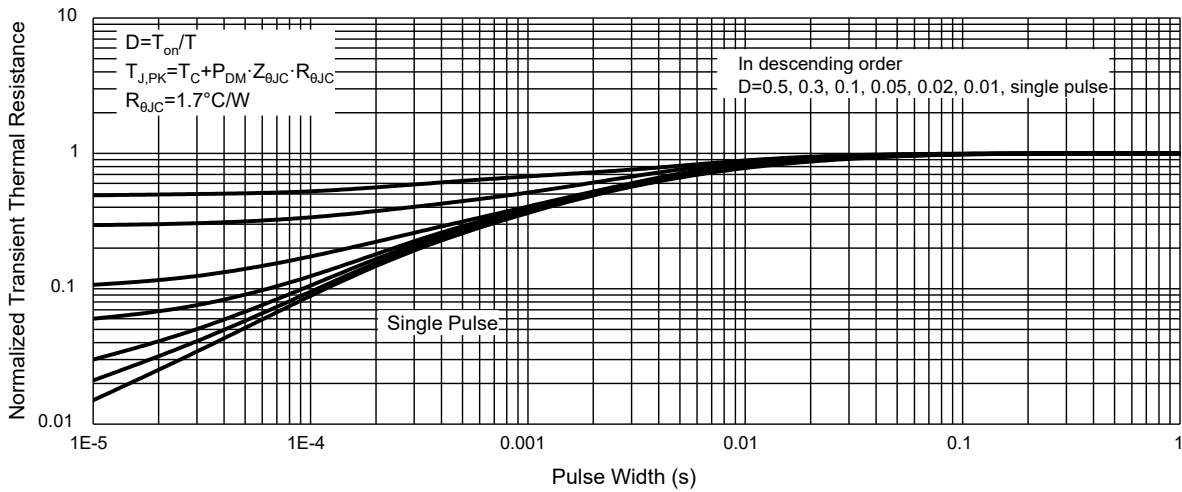


Fig. 8 - Normalized Maximum Transient Thermal Impedance



## Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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